NSN 5961-01-623-9855

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-623-9855 **Inclosure Material:** Plastic **End Application:** B-1 **Mounting Method:** Threaded hole Voltage Rating In Volts Per Characteristic: 5.0 source supply voltage **Current Rating Per Characteristic:** 65.2 amperes base current, dc **Power Rating Per Characteristic:** 60.0 watts peak gate power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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